

DESCRIPTION

The GLF72120 and GLF72122 are an advanced technology fully integrated I_QSmart™ load switch device with reverse current blocking (RCB) protection and slew rate control of the output voltage.

The GLF72120 and GLF72122 offer industry reverse current blocking (RCB) protection performance, featuring an ultra-low threshold voltage. The GLF72120 and GLF72122 minimize reverse current flow in the event that the V_{OUT} pin voltage exceeds the V_{IN} voltage.

The GLF72120 and GLF72122 have an industry leading power efficiency. It features an on-resistance (R_{ON}) as low as 14 mΩ typical at 5.5 V, reducing power loss during conduction. The GLF72120 and GLF72122 also features ultra-low shutdown current (I_{SD}) to reduce power loss and battery drain in the off state. When EN is pulled low, and the output is grounded, the GLF72120 and GLF72122 can achieve an I_{SD} as low as 56 nA typical at 5.5 V.

The GLF72120 and GLF72122 load switch device supports an industry leading wide input voltage range that helps to improve system operating life and overall performance. One GLF7212x device can be used in multiple voltage rail applications which helps mitigate inventory management and reduces BOM cost.

The GLF72120 and GLF72122 load switch device are in a 0.97 mm x 1.47 mm x 0.55 mm chip scale package with 6 bumps and a 0.5 mm pitch.

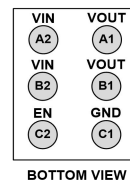
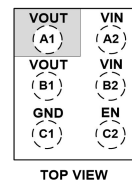
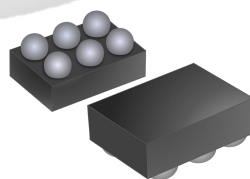
FEATURES

- Supply Voltage Range: 1.5 V to 5.5 V
6 V_{abs} max
- Low R_{ON}: 14 mΩ Typ at 5.5 V_{IN}
- Ultra-Low I_Q: 1.3 μA Typ at 5.5 V_{IN}
- Ultra-Low I_{SD}: 56 nA Typ at 5.5 V_{IN}
- I_{OUT} Max: 4 A
- Reverse Current Blocking Protection
- Controlled V_{OUT} Rise Time
GLF72120: 730 μs at 3.3 V_{IN}
GLF72122: 2000 μs at 3.3 V_{IN}
- Internal EN Pull-Down Resistor
- 0.97 mm x 1.47 mm x 0.55 mm Wafer Level Chip Scale Package

APPLICATIONS

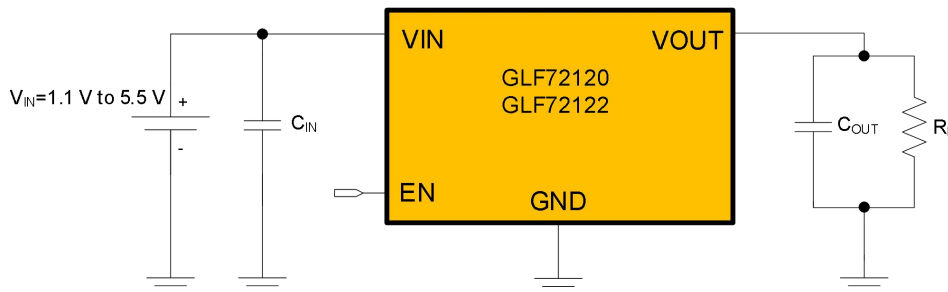
- Mobile Devices
- Wearabl
- Low Power Subsystems

PACKAGE



0.97 mm x 1.47 mm x 0.55 mm, 0.5 mm Pitch

APPLICATION DIAGRAM



DEVICE INFORMATION

Part Number	Top Mark	V _{OUT} Rising Time, Tr Typ [μs] at 3.3 V _{IN}	EN Activity	Tape and Reel Packaging
GLF72120	RA	730	High	3000 Pieces on 7 inch reel
GLF72122	RC	2000		

FUNCTIONAL BLOCK DIAGRAM

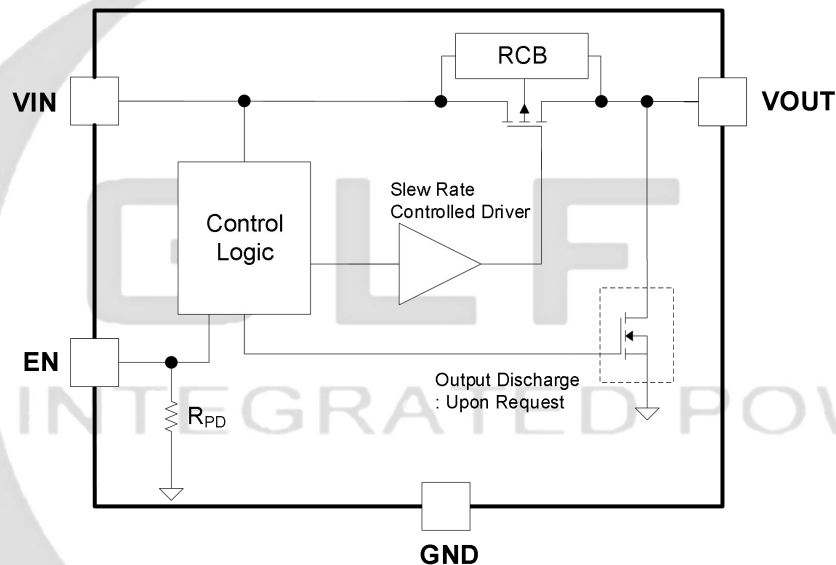
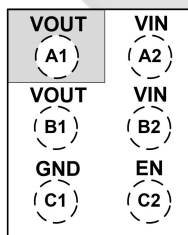


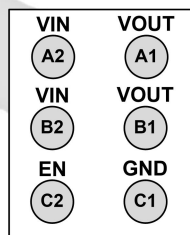
Figure 1. Functional Block Diagram

PIN CONFIGURATION

PIN DEFINITION



TOP VIEW



BOTTOM VIEW

Pin #	Name	Description
A1, B1	VOUT	Switch Output
A2, B2	VIN	Switch Input. Supply Voltage
C1	GND	Ground
C2	EN	Enable to control the switch

Figure 2. 0.97 mm x 1.47 mm x 0.55 mm WLCSP

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V _{IN} , V _{OUT} , V _{EN}	Each Pin Voltage Range to GND	-0.3	6	V
I _{OUT}	Maximum Continuous Switch Current		4	A
P _D	Power Dissipation at T _A = 25 °C		1.2	W
T _{STG}	Storage Junction Temperature	-65	150	°C
T _J	Maximum Junction Temperature		150	°C
T _A	Operating Temperature Range	-40	85	°C
θ _{JA}	Thermal Resistance, Junction to Ambient (Measured using 2S2P JEDEC std. PCB.)		85	°C/W
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	±6	kV
		Charged Device Model, JESD22-C101	±2	

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	1.5	5.5	V
T _A	Ambient Operating Temperature	-40	+85	°C

ELECTRICAL CHARACTERISTICS

Typical values are at $V_{IN} = 3.3\text{ V}$ and $T_A = 25\text{ °C}$. Unless otherwise noted

Symbol	Parameter	Conditions		Min	Typ	Max	Units
Basic Operation							
I _Q	Supply Current	EN = Enable, I _{OUT} = 0 mA, V _{IN} = V _{EN} = 5.5 V			1.3	2	μA
		EN= Enable, I _{OUT} = 0 mA, V _{IN} =V _{EN} = 5.5 V, T _A = 85 °C ⁽³⁾			1.4		
I _{SD}	Shutdown Current on	EN= Disable, I _{OUT} = 0 mA, V _{IN} = 1.5 V			5	20	nA
		EN= Disable, I _{OUT} = 0 mA, V _{IN} = 3.3 V			8		
		EN= Disable, I _{OUT} = 0 mA, V _{IN} = 4.2 V			12		
		EN= Disable, I _{OUT} = 0 mA, V _{IN} = 5.5 V			56	100	
		EN= Disable, I _{OUT} = 0 mA, V _{IN} = 5.5 V, T _A = 85 °C ⁽³⁾			1000		
R _{ON}	On-Resistance	V _{IN} = 5.5 V I _{OUT} = 500 mA	T _A = 25 °C		14	19	mΩ
			T _A = 85 °C ⁽³⁾		16		
		V _{IN} = 3.3 V, I _{OUT} = 500 mA	T _A = 25 °C		18	23	
			T _A = 85 °C ⁽³⁾		21		
		V _{IN} = 1.8 V, I _{OUT} = 300 mA	T _A = 25 °C ⁽³⁾		30		
		V _{IN} = 1.5 V, I _{OUT} = 100 mA	T _A = 25 °C		37	42	
V _{IH}	EN Input Logic High Voltage	V _{IN} = 1.5 to 5.5 V		1.2			V
V _{IL}	EN Input Logic Low Voltage	V _{IN} = 1.5 to 5.5 V				0.4	
R _{EN}	EN pull down resistance	Internal Resistance			10		MΩ
I _{EN}	EN Source or Sink Current	V _{EN} = V _{IN} or GND			0.5	1	μA
V _{RCB_TH}	RCB Protection Threshold Voltage	V _{OUT} – V _{IN}			37		mV
V _{RCB_RL}	RCB Protection Release Voltage	V _{IN} – V _{OUT}			37		
Switching Characteristics ⁽²⁾ , GLF72120							
t _{dON}	Turn-On Delay	R _{OUT} = 150 Ω, C _{OUT} = 1.0 μF			450		μs
t _R	V _{OUT} Rise Time				730		
t _{dOFF}	Turn-Off Delay ⁽³⁾	R _{OUT} = 150 Ω, C _{OUT} = 1.0 μF			20		
t _F	V _{OUT} Fall Time ⁽³⁾				360		
Switching Characteristics ⁽²⁾ , GLF72122							
t _{dON}	Turn-On Delay	R _{OUT} = 150 Ω, C _{OUT} = 1.0 μF			1500		μs
t _R	V _{OUT} Rise Time				2000		
t _{dOFF}	Turn-Off Delay ⁽³⁾	R _{OUT} = 150 Ω, C _{OUT} = 1.0 μF			25		
t _F	V _{OUT} Fall Time ⁽³⁾				300		

- Notes:
- I_Q does not include Enable pull down current through the pull-down resistor R_{EN} .
 - $t_{ON} = t_{dON} + t_R$, $t_{OFF} = t_{dOFF} + t_F$
 - By design; characterized, not production tested

TIMING DIAGRAM

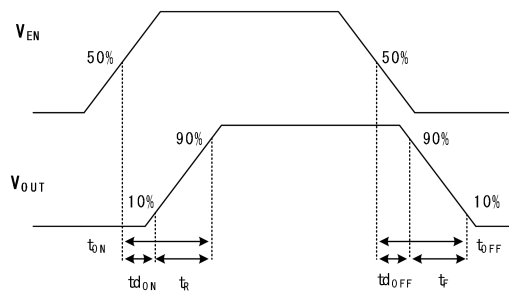


Figure 3. Timing Diagram

TYPICAL PERFORMANCE CHARACTERISTICS

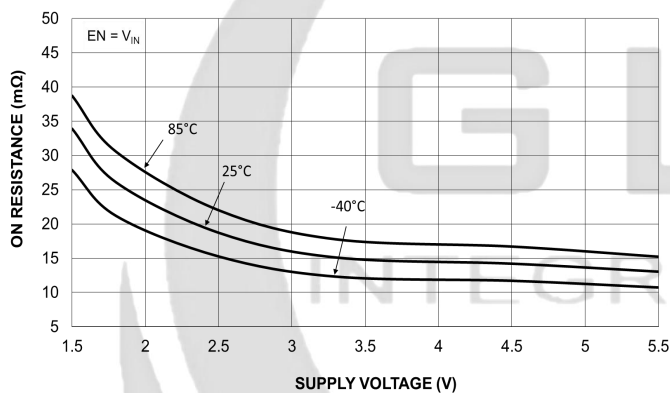


Figure 4. On-Resistance vs. Supply Voltage

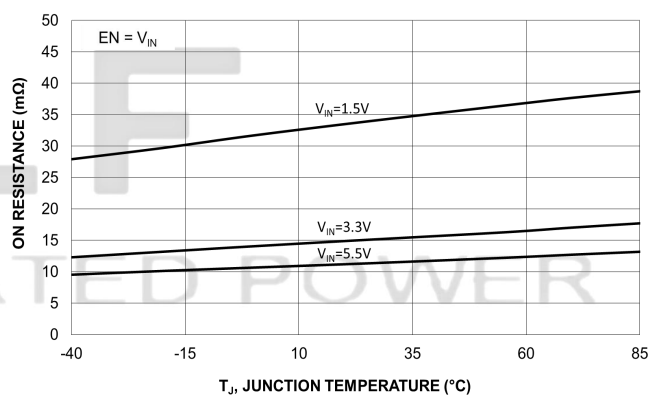


Figure 5. On-Resistance vs. Temperature

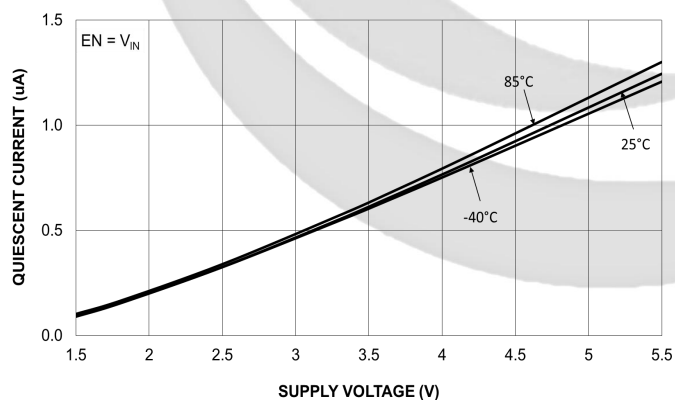


Figure 6. Quiescent Current vs. Supply Voltage

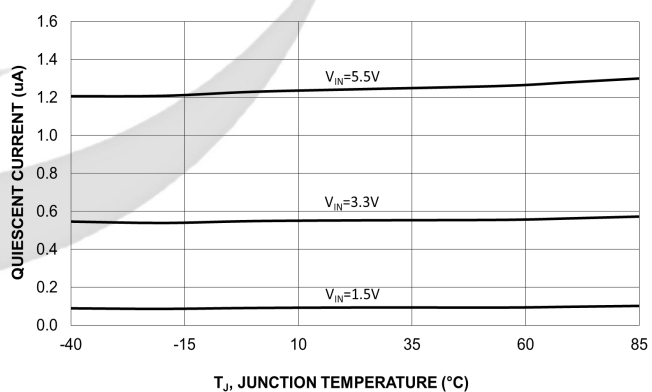


Figure 7. Quiescent Current vs. Temperature

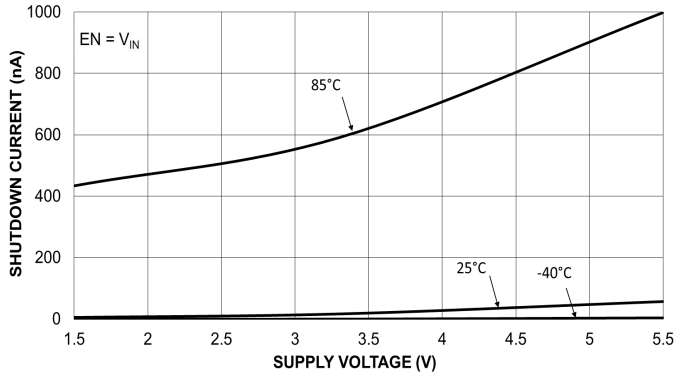


Figure 8. Shutdown Current vs. Supply Voltage

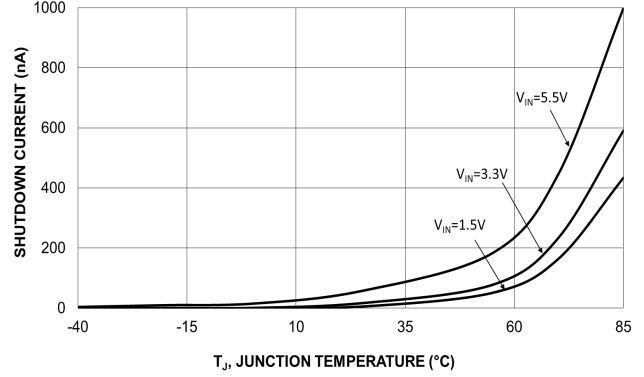


Figure 9. Shutdown Current vs. Temperature

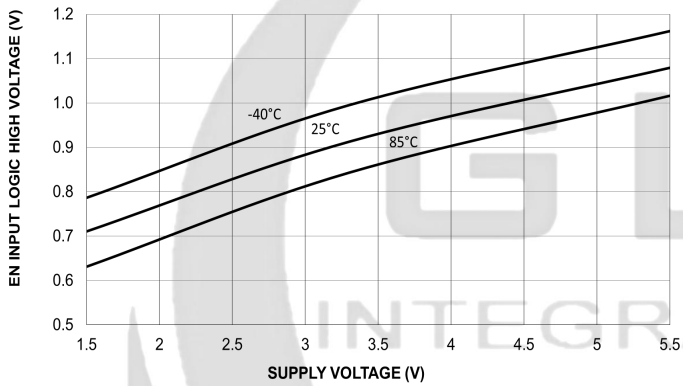


Figure 10. EN Input Logic High Threshold

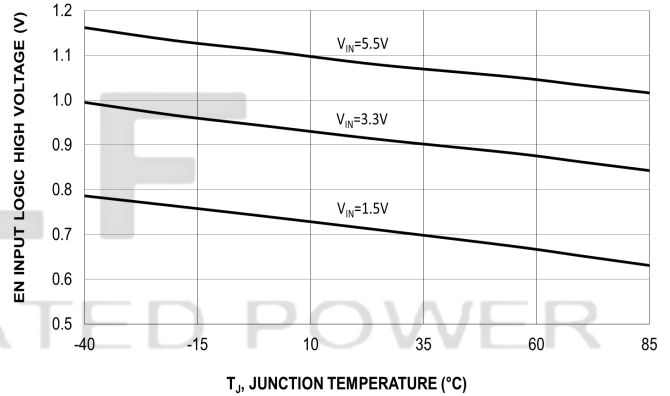


Figure 11. EN Input Logic High Threshold Vs. Temperature

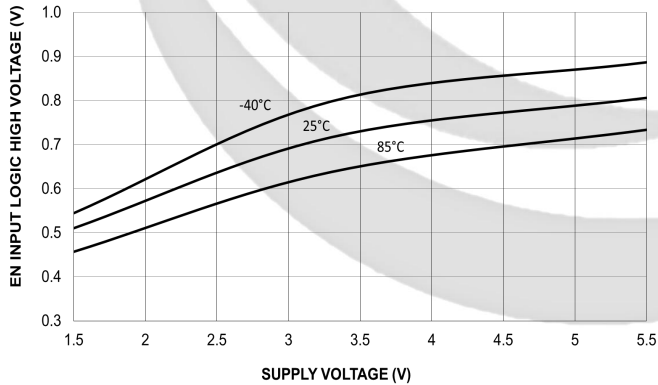


Figure 12. EN Input Logic Low Threshold

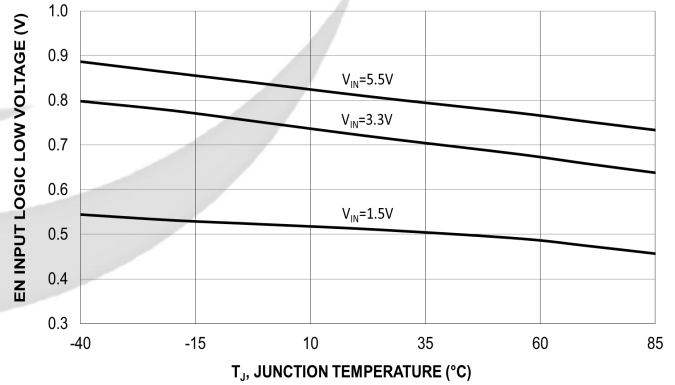


Figure 13. EN Input Logic Low Threshold Vs. Temperature

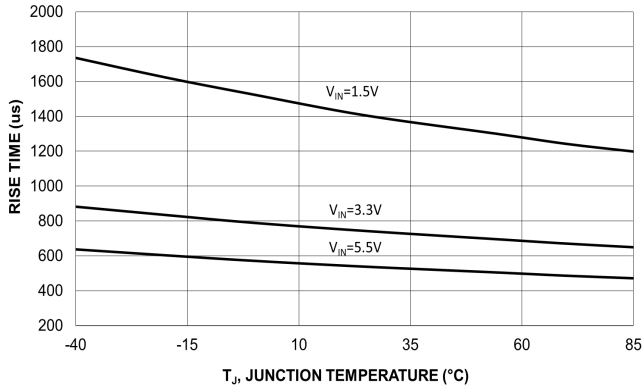


Figure 14. V_{OUT} Rise Time vs. Temperature, GLF72120

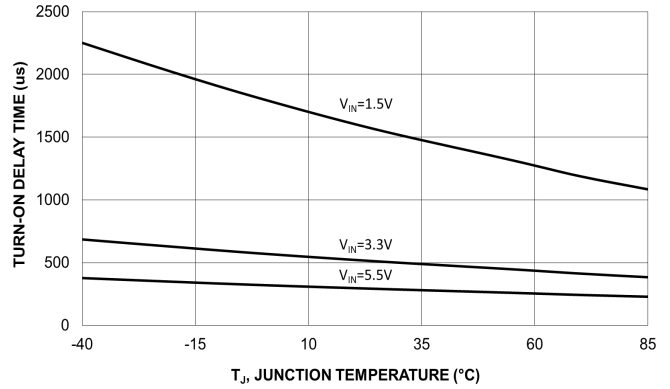


Figure 15. Turn-On Delay Time vs. Temperature, GLF72120

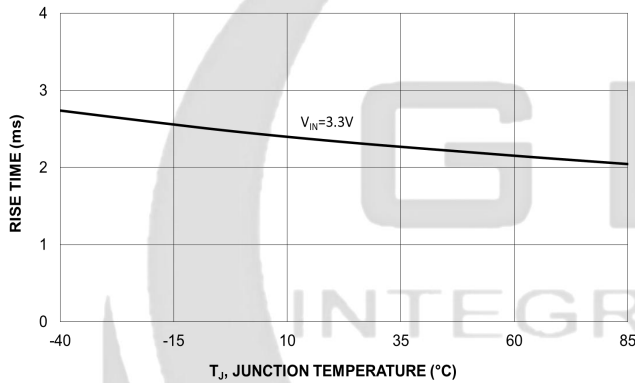


Figure 16. V_{OUT} Rise Time vs. Temperature, GLF72122

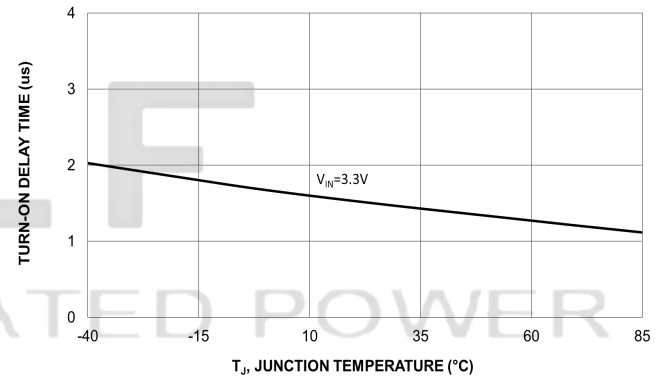


Figure 17. Turn-On Delay Time vs. Temperature, GLF72122

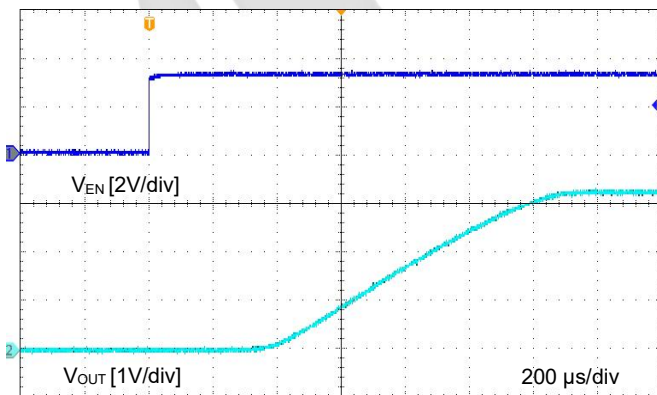


Figure 18. Turn-On Response, GLF72120
V_{IN}= 3.3 V, C_{IN}= 1.0 μF, C_{OUT}= 1.0 μF, R_L= 150 Ω

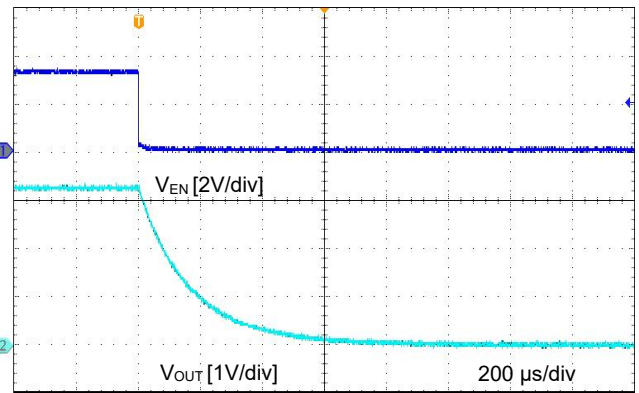


Figure 19. Turn-Off Response, GLF72120
V_{IN}= 3.3 V, C_{IN}= 1.0 μF, C_{OUT}= 1.0 μF, R_L= 150 Ω

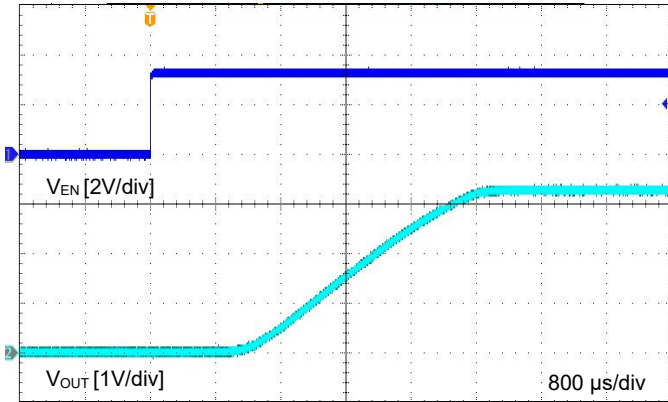


Figure 20. Turn-On Response, GLF72122
 $V_{IN} = 3.3\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 1.0\text{ }\mu\text{F}$, $R_L = 150\text{ }\Omega$

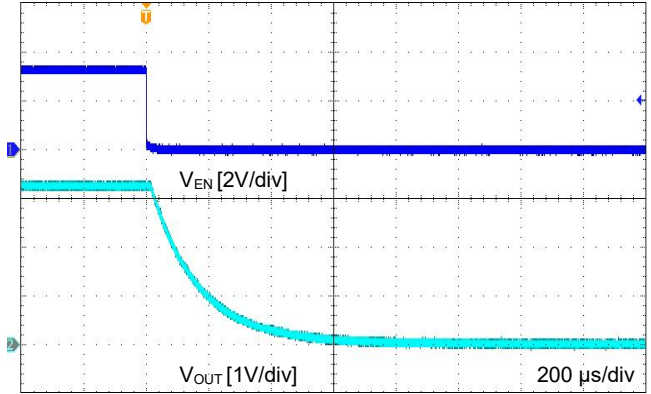


Figure 21. Turn-Off Response, GLF72122
 $V_{IN} = 3.3\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 1.0\text{ }\mu\text{F}$, $R_L = 150\text{ }\Omega$

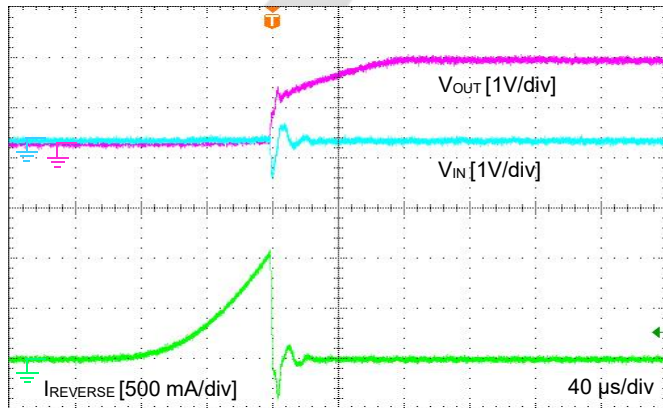


Figure 22. Reverse Current Blocking
 $V_{IN} = 3.3\text{ V}$, $V_{OUT} = \text{From } 3.3\text{ V to } 4\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 1.0\text{ }\mu\text{F}$

APPLICATION INFORMATION

The GLF72120 and GLF72122 are an integrated 4 A ultra-low leakage I_QSmart™ load switch with the slew rate control of the output voltage to limit the inrush current during turn on. Each device is capable of operating over a wide input range from 1.5 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current to avoid unwanted standby current and save limited input power supply. The package is 0.97 mm x 1.47 mm x 0.55 mm wafer level chip scale package saving space in compact applications and it has 6 bumps, 0.5 mm pitch for manufacturing availability.

Input Capacitor

The GLF72120 and GLF72122 require an input capacitor to function. A 1μF capacitor is recommended to be placed close to V_{IN} pin to reduce a voltage drop on the input power rail caused by transient inrush current at start-up. A higher input capacitor value can be used to attenuate the input voltage drop.

Output Capacitor

A 0.1 μF capacitor or higher values can be able to prevent undershoot caused by parasitic inductance on board traces at switching off and improve reliability of a controlled voltage rail. The C_{OUT} should be placed close to V_{OUT} and GND pins.

EN Pin

The GLF72120 and GLF72122 can be activated by EN pin high. Note that the EN pin has an internal pull-down resistor to maintain a reliable status without EN signal applied from an external controller.

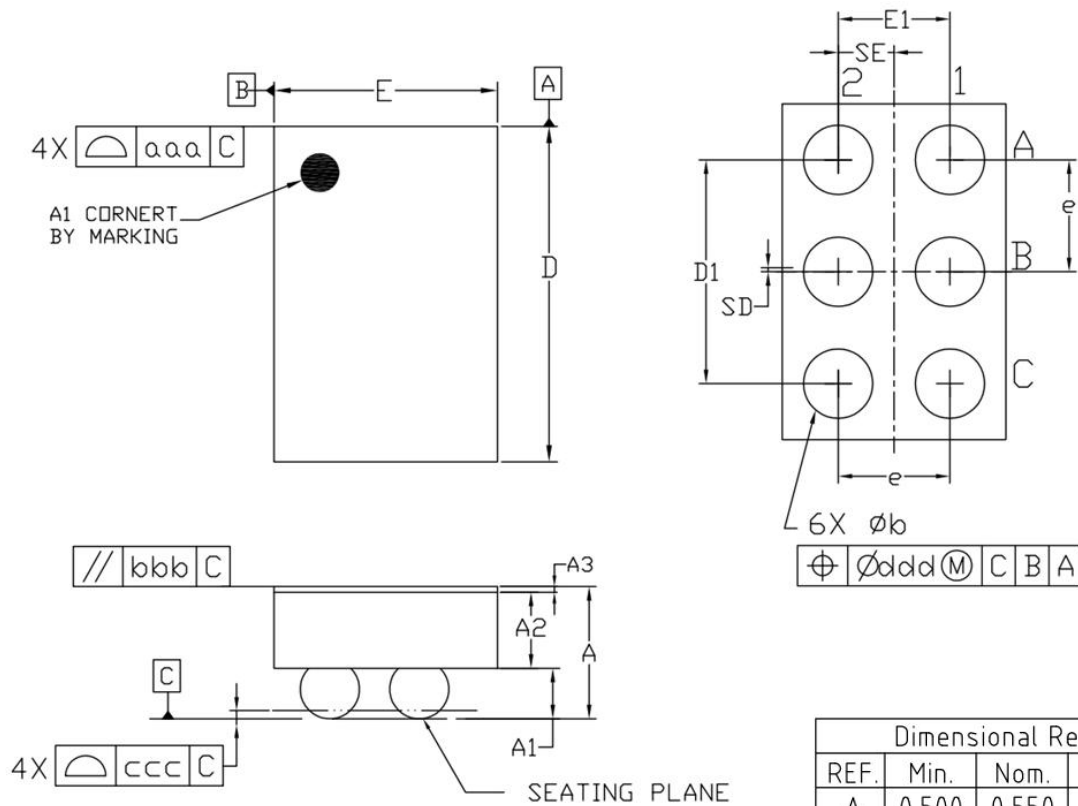
Reverse Current Blocking

The GLF72120 and GLF72122 have a built-in reverse current blocking protection which always monitors the output voltage level regardless of the status of EN pin to check if it is greater than the input voltage. When the output voltage goes beyond the input voltage by 37 mV, that is the reverse current blocking protection threshold voltage (V_{RCB_TH}), the reverse current blocking function block turns off the switch. Note that some reverse current can occur until the V_{RCB_TH} is triggered. The main switch will resume normal operation when the output voltage drops below the input source by the reverse current blocking protection release voltage (V_{RCB_RL}).

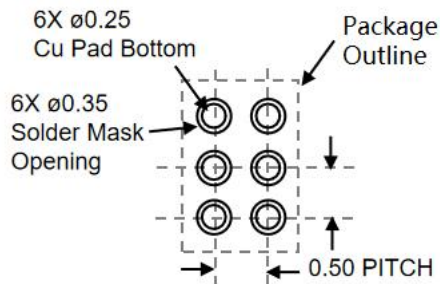
Board Layout

All traces should be as short as possible to minimize parasitic inductance effect. Wide traces for V_{IN}, V_{OUT}, and GND will be better to reduce parasitic effects at dynamic operations and improve thermal performance at high load current.

PACKAGE OUTLINE



Recommended Footprint



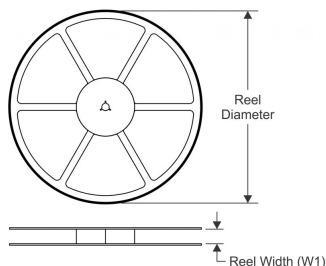
Notes

1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES)
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
3. A3: BACKSIDE LAMINATION

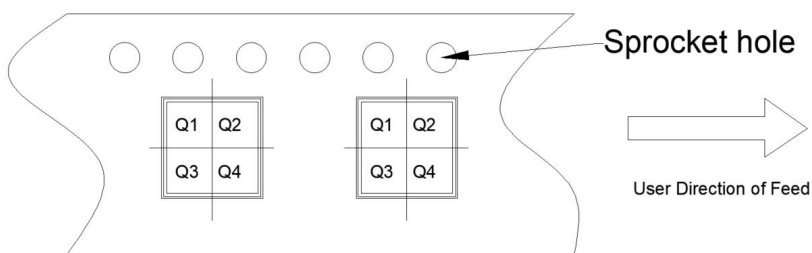
Dimensional Ref.			
REF.	Min.	Nom.	Max.
A	0.500	0.550	0.600
A1	0.225	0.250	0.275
A2	0.250	0.275	0.300
A3	0.020	0.025	0.030
D	1.460	1.470	1.485
E	0.960	0.970	0.985
D1	0.950	1.000	1.050
E1	0.450	0.500	0.550
b	0.260	0.310	0.360
e	0.500 BSC		
SD	0.000 BSC		
SE	0.250 BSC		
Tol. of Form&Position			
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		

TAPE AND REEL INFORMATION

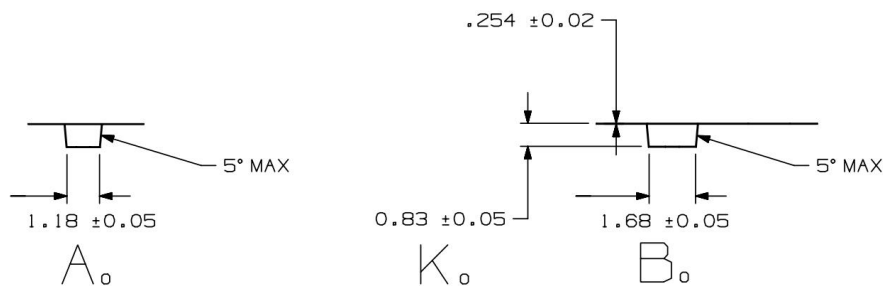
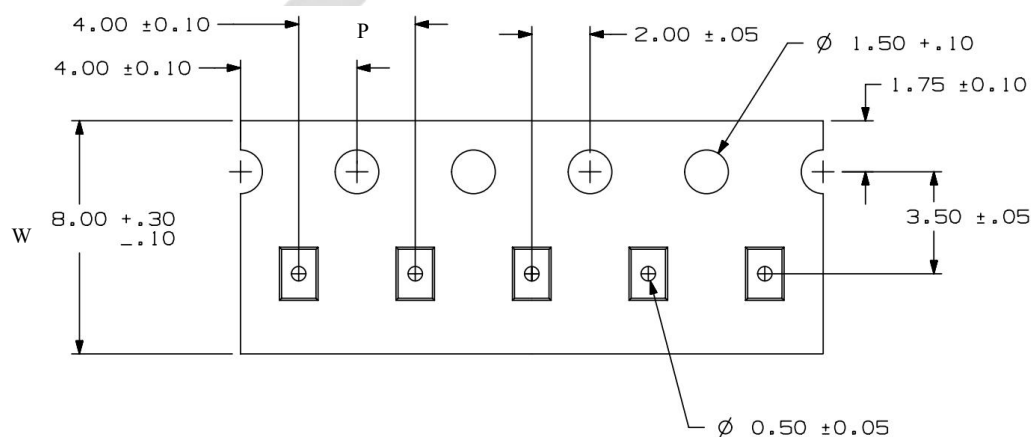
REEL DIMENSIONS



QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE



TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	A0	B0	K0	P	W	Pin1
GLF72120	WLCSP	6	3000	180	9	1.18	1.68	0.83	4	8	Q1
GLF72122	WLCSP	6	3000	180	9	1.18	1.68	0.83	4	8	Q1

Remark:

A0: Dimension designed to accommodate the component width

B0: Dimension designed to accommodate the component length

C0: Dimension designed to accommodate the component thickness

W: Overall width of the carrier tape

P1: Pitch between successive cavity centers

SPECIFICATION DEFINITIONS

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Parameters including the typical, minimum, and maximum values are desired, or target. GLF reserves the right to change contents at any time without warning or notification. A target specification will not guarantee the future production of the device.	Design / Development
Preliminary Specification	This is a draft version of a product specification which is under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification will not guarantee the future production of the device.	Qualification
Product Specification	This document represents the characteristics of the device.	Production

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